



Clock Oscillators Surface Mount Type KC5032C-C3 Series (K30-3C Series)



CMOS/ 3.3V/ 5.0× 3.2mm



Features

- Miniature ceramic package
 - Highly reliable with seam welding
 - CMOS output
 - Supply voltage $V_{CC}=3.3V$
 - $\pm 25 \times 10^{-6}$ to $\pm 20 \times 10^{-6}$ available

Table 1

Freq. Tol. Code	$\times 10^{-6}$	Operating Temperature Range (°C)	Note
0	± 50		Standard specifications
S	± 30	-10 to +70	
U	± 25		
W	± 20		
F	± 100		
C	± 50	-40 to +85	With only certain frequencies

How to Order

KC5032C 25.0000 C 3 0 E 00

- ① Type (5.0×3.2mm SMD)
 - ② Output Frequency
 - ③ Output Type (CMOS)
 - ④ Supply Voltage (3.3V)
 - ⑤ Frequency Tolerance (See Table 1)
 - ⑥ Symmetry/ INH Function
(45/ 55%, Stand-by)
 - ⑦ Customer Special Model Suffix
(STD Specification is “00”)

Packaging (Tape & Reel 1000 pcs./ reel)

Specifications

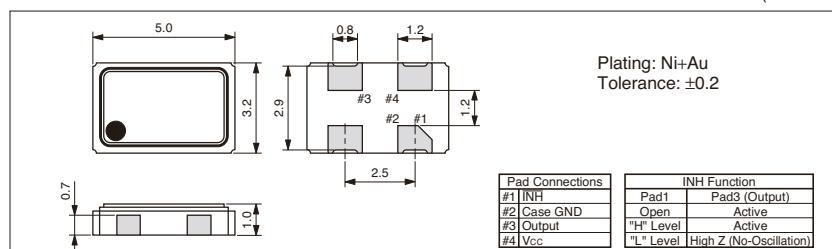
Item	Symbol	Conditions		Min.	Max.	Units
Output Frequency Range	f _o			1.8	170	MHz
Frequency Tolerance	f _{tol}	Initial tolerance, Operating temperature range, Rated power supply voltage change, Load change, Aging (1 year @25°C), Shock and vibration	Op. Temp.: -40 to +85°C	-100	+100	$\times 10^{-6}$
			Op. Temp.: -10 to +70°C / -40 to +85°C	-50	+50	
			Op. Temp.: -10 to +70°C	-30	+30	
			Op. Temp.: -10 to +70°C	-25	+25	
			Op. Temp.: -10 to +70°C	-20	+20	
Storage Temperature Range	T _{stg}			-55	+125	°C
Operating Temperature Range	T _{use}	Standard Specifications		-10	+70	°C
		Extend (Option)		-40	+85	°C
Max. Supply Voltage	—			-0.5	+7	V
Supply Voltage	V _{CC}	Freq. Tol.Code: 0, S, F		2.97	3.63	V
		Freq. Tol.Code: U, G		3.14	3.46	
		Freq. Tol.Code: W		3.20	3.40	
Current Consumption (Maximum Loaded)	I _{CC}	1.8≤f _o ≤20MHz		—	10	mA
		20<f _o ≤40MHz		—	15	
		40<f _o ≤60MHz		—	30	
		60<f _o ≤100MHz		—	35	
		100<f _o ≤135MHz		—	45	
		135<f _o ≤170MHz		—	60	
Stand-by Current	I _{std}	1.8≤f _o ≤135MHz		—	10	μA
		135<f _o ≤170MHz		—	150	
Symmetry	SYM	@50% V _{CC}		45	55	%
Rise/ Fall Time (10% V _{CC} to 90% V _{CC} Maximum Loaded)	t _{r/ tf}	1.8≤f _o ≤26MHz		—	10	ns
		26<f _o ≤45MHz		—	8	
		45<f _o ≤100MHz		—	5	
		100<f _o ≤170MHz		—	2.5	
Low Level Output Voltage	V _{OL}	I _{OL} =8mA		—	10% V _{CC}	V
High Level Output Voltage	V _{OH}	I _{OH} =8mA		90% V _{CC}	—	V
CMOS Load	L _{_CMOS}	CMOS Output		—	15	pF
Input Voltage Range	V _{IN}			0	V _{CC}	V
Low Level Input Voltage	V _{IL}			—	30% V _{CC}	V
High Level Input Voltage	V _{IH}			70% V _{CC}	—	V
Disable Time	t _{dis}			—	150	ns
Enable Time	t _{ena}			—	5	ms
Start-up Time	t _{str}	@Minimum operating voltage to be 0 sec.		—	10	ms
1 Sigma Jitter	J _{Sigma}	Measured with Wavecrest DTS-2079 VIISI 6.3.1	1.8≤f _o <40MHz	—	8	ps
			40≤f _o ≤100MHz	—	5	ps
			100<f _o ≤170MHz	—	4	ps
			1.8≤f _o <40MHz	—	80	ps
Peak to Peak Jitter	J _{PK-PK}		40≤f _o ≤100MHz	—	40	ps
			100<f _o ≤170MHz	—	30	ps

Note: All electrical characteristics are defined at the maximum load and operating temperature range.

Please contact us for inquiry about operating temperature range, available frequencies and other conditions.

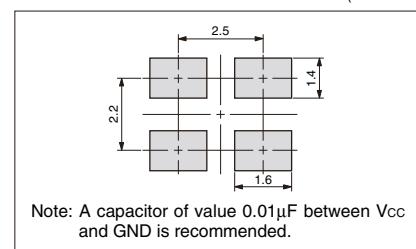
Dimensions

(Unit: mm)



Recommended Land Pattern

(Unit: mm)



Note: A capacitor of value $0.01\mu\text{F}$ between V_{CC} and GND is recommended.

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